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## **Supporting Information**

# Matrix-isolated trifluoromethylthiyl radical: sulfur atom transfer, isomerization and oxidation reactions

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#### **Experimental and computational details**

### Sample preparation

Bis(trifluoromethyl)disulfane oxide, CF<sub>3</sub>S(O)SCF<sub>3</sub>, was synthesized by the reaction of CF<sub>3</sub>S(O)Cl (95%, Macklin) with AgSCF<sub>3</sub> (>95%, TCl). Briefly, commercial trifluomethylsulfinyl chloride (1 mmol, 0.15g) was condensed into a reaction vessel containing silver trifluoromethanethiolate (1.5mmol, 0.31g) and propylene carbonate (1 mL). The mixture was stirred at -50 °C for 72 h. The volatile products were separated by passing through three successive cold U-traps (-64, -86, -196 °C). Pure CF<sub>3</sub>S(O)SCF<sub>3</sub> was retained in the middle trap. The purity of the substance was checked by gas phase IR (INSA OPTICS FOLI10-R, v = 1224, 1181, 1112, 763 cm<sup>-1</sup>) and NMR spectroscopy (Bruker Avance III HD 500 spectrometer). <sup>13</sup>C NMR (125 MHz, CDCl<sub>3</sub>):  $\delta$  = 124.7 (q, -S(O)CF<sub>3</sub>), 128.5 (q, -SCF<sub>3</sub>) ppm. <sup>19</sup>F NMR (470 MHz, CDCl<sub>3</sub>):  $\delta$  = -33.8 (s, -S(O)CF<sub>3</sub>).

Gases Ar ( $\geq$  99.999%, Linde), N<sub>2</sub> ( $\geq$  99.999%, Linde), Ne ( $\geq$  99.999%, Messer), and O<sub>2</sub> ( $\geq$  99.999%, Linde) were used without further purification. For the isotope labeling experiments, <sup>15</sup>N<sub>2</sub> (98 atom %, Aldrich) and <sup>18</sup>O<sub>2</sub> (97 atom %, Aldrich) were used.

### Matrix-isolation IR spectroscopy

Matrix IR spectra were recorded on a FT-IR spectrometer (Bruker 70V) in a reflectance mode using a transfer optic. A KBr beam splitter and MCT detector were used in the mid-IR region (5000–400 cm<sup>-1</sup>). Typically, 200 scans at a resolution of 0.5 cm<sup>-1</sup> were co-added for each spectrum. Gaseous CF<sub>3</sub>S(O)SCF<sub>3</sub> was mixed by Ar, Ne or N<sub>2</sub> (1:1000). As for the oxidation experiment, CF<sub>3</sub>S(O)SCF<sub>3</sub> was mixed by oxygen and Ar, Ne or N<sub>2</sub> (1:1000) at room temperature. Then the mixture (sample:O<sub>2</sub>:dilution gas=1:50:1000, estimated) was passed through an aluminum oxide furnace (o.d 2.0 mm, i.d. 1.0 mm), which can be heated over a length of ca. 25 mm by tantalum wire (o.d. 2.0 mm, resistance 0.4  $\Omega$ ) and immediately deposited (2 mmol h<sup>-1</sup>) in a high vacuum (~10<sup>-6</sup> pa) onto the Au-plated Cu block matrix support (10 K for N<sub>2</sub> and Ar matrix, 3 K for Ne matrix) using a closed-cycle helium cryostat (Sumitomo Heavy Industries, SRDK-408D2-F50H) inside the vacuum chamber. Temperatures at the second stage of the cold head were controlled and monitored using an East Changing TC 290 digital cryogenic temperature controller a Silicon Diode (DT-670). The voltage and current used in the pyrolysis experiments were 5.50 V and 3.12 A, respectively. Photolysis experiments were performed using ArF excimer laser (Gamlaser EX5/250, 3 Hz, 193 nm), Nd<sup>3+</sup>: YAG laser (266 nm, MPL-F-266, 10 mW), UV lamp (365 nm, 24 W) and blue-light LED (440 nm).

### Matrix-isolation UV-vis spectroscopy

Matrix UV-vis spectra were recorded on a Perkin Elmer Lambda 850+ spectrometer (spectral range of 190– 800 nm with a scanning speed of 1 nm s<sup>-1</sup>). The high-vacuum flash pyrolysis products using the similar furnace (o.d 2.0 mm, i.d. 1.0 mm) were deposited onto the CaF<sub>2</sub> matrix support using a closed-cycle helium cryostat (Sumitomo Heavy Industries, SRDK-408D2-F50H) inside the vacuum chamber. Temperatures at the second stage of the cold head were controlled and monitored using a Lake Shore 335 digital cryogenic temperature controller a Silicon Diode (DT-670). The voltage and current used in the pyrolysis experiments were 5.50 V and 3.12 A, respectively. Photolysis experiments were performed using Ar Fexcimer laser (Gamlaser EX5/250, 3 Hz, 193 nm), Nd<sup>3+</sup>: YAG laser (266 nm, MPL-F-266, 10 mW), UV lamp (365 nm, 24 W) and blue-light LED (440 nm).

#### Quantum chemical calculation methods

Structures and IR frequencies of stationary points were calculated using the DFT B3LYP<sup>[1]</sup>, BP86<sup>[2]</sup> and MPW1PW91<sup>[3]</sup> methods with the 6-311+G(3df) basis set. Accurate relative energies of the species were further calculated using the complete basis set (CBS-QB3).<sup>[4]</sup> Local minima were confirmed by vibrational frequency analysis, and transition states were further confirmed by intrinsic reaction coordinate (IRC) calculations.<sup>[5]</sup> The time-dependent TD-B3LYP/6-311+G(3df)<sup>[6]</sup> and EOM-CCSD/aug-cc-pV(T+d)Z<sup>[7]</sup> methods were performed for the prediction of vertical excitations. These computations were performed using the Gaussian 09 software package.<sup>[8]</sup> To provide detailed insight into the lowest excited states of CF<sub>3</sub>S•, •CF<sub>2</sub>SF and CF<sub>3</sub>SOO•, calculations with the complete active space self-consistent field (CASSCF),<sup>[9]</sup> followed by the internally contracted multireference configuration interaction including the Davidson correction MRCI+Q<sup>[10]</sup> were used. These calculations were done using the optimized equilibrium geometries at the CCSD(T)/aug-cc-pv(T+d)z level. All these ab initio calculations were performed with MOLPRO 2019 program.<sup>[11]</sup>



**Figure S1.** (A) IR spectrum of a 1:1000 mixture of  $CF_3S(O)SCF_3/Ar$  at 10 K. (B) IR spectrum of the matrixisolated high-vacuum flash pyrolysis (HVFP, 400 °C) products of a 1:1000 mixture of  $CF_3S(O)SCF_3/Ar$  at 10 K.



**Figure S2.** (A) IR spectrum of a 1:1000 mixture of  $CF_3S(O)SCF_3/Ne$  at 3 K. (B) IR spectrum of the matrixisolated high-vacuum flash pyrolysis (HVFP, 400 °C) products of a 1:1000 mixture of  $CF_3S(O)SCF_3/Ne$  at 3 K.



**Figure S3.** (A) IR spectrum of a 1:1000 mixture of  $CF_3S(O)SCF_3/N_2$  at 10 K. (B) IR spectrum of the matrixisolated high-vacuum flash pyrolysis (HVFP, 400 °C) products of a 1:1000 mixture of  $CF_3S(O)SCF_3/N_2$  at 10 K.



**Figure S4.** IR spectra in the region of  $1190-1100 \text{ cm}^{-1}$  obtained: A) 1 h of sample deposition of high-vacuum flash pyrolysis products of CF<sub>3</sub>S(O)SCF<sub>3</sub>/Ar at 10 K, B) after annealing the matrix to 25 K for 1 min, C) after annealing the matrix to 25 K for 5 min, D) after keeping the matrix at 25 K.



**Figure S5.** IR spectra in the region of  $1190-1100 \text{ cm}^{-1}$  obtained: A) 1 h of sample deposition of high-vacuum flash pyrolysis products of CF<sub>3</sub>S(O)SCF<sub>3</sub>/N<sub>2</sub> at 10 K, B) after annealing the matrix to 25 K for 30 s, C) after annealing the matrix to 25 K for 5 min, D) after keeping the matrix at 25 K.



**Figure S6.** (A) IR difference spectrum showing the changes of the HVFP products of a 1:1000 mixture of  $CF_3S(O)SCF_3/N_2$  upon UV-light irradiation (365 nm, 40 min) in a solid  $N_2$ -matrix at 10 K. (B) IR difference spectrum showing the changes of the matrix upon further UV-laser irradiation (266 nm, 15 min) at 10 K.



**Figure S7.** (A) IR difference spectrum showing the changes of the HVFP products of a 1:1000 mixture of  $CF_3S(O)SCF_3/N_2$  upon an ArF excimer laser irradiation (193 nm, 30 min) in a solid N<sub>2</sub>-matrix at 10 K. (B) IR difference spectrum showing the changes of the matrix upon further UV-light irradiation (365 nm, 5 min) at 10 K.



**Figure S8.** (A) IR difference spectrum showing the changes of the HVFP products of a 1:1000 mixture of  $CF_3S(O)SCF_3/Ar$  upon an ArF excimer laser irradiation (193 nm, 35 min) in a solid Ar-matrix at 10 K. (B) IR difference spectrum showing the changes of the matrix upon further UV-light irradiation (365 nm, 10 min) at 10 K.



**Figure S9.** IR difference spectrum showing the changes of the HVFP products of a 1:600 mixture of  $CF_3S(O)SCF_3/CO$  upon UV-light irradiation (365 nm, 5 min) at 16 K.



**Figure S10.** (A) IR spectrum of the HVFP products of a 1:50:1000 mixture of  $CF_3S(O)SCF_3/O_2/N_2$  at 10 K. (B) IR spectrum of the HVFP products of a 1:25:25:1000 mixture of  $CF_3S(O)SCF_3/O_2/N_2$  at 10 K.



**Figure S11.** (A) IR spectrum of the HVFP products of a 1:50:1000 mixture of  $CF_3S(O)SCF_3/O_2/Ne$  at 3 K. (B) IR difference spectrum showing the change of the matrix upon blue-light LED irradiation (440 nm, 70 min) at 3 K.

CF₃SSO●		CF₃SOS●		CF₃S(O)S•		CF₃OSS●	
B3LYP	MPW1PW91	B3LYP	MPW1PW91	B3LYP	MPW1PW91	B3LYP	MPW1PW91
1160.5 (222)	1207.9 (218)	1161.3 (220)	1208.6 (222)	1220.7 (283)	1265.9 (285)	1225.1 (486)	1270.9 (446)
1148.0 (234)	1196.1 (232)	1150.6 (238)	1195.9 (240)	1207.8 (253)	1250.9 (254)	1168.9 (610)	1210.2 (341)
1106.6 (92)	1138.0 (101)	1104.0 (417)	1138.9 (407)	1155.9 (43)	1198.3 (48)	1157.6 (342)	1205.3 (629)
1074.0 (423)	1106.4 (416)	759.0 (14)	798.5 (46)	1063.9 (411)	1101.3 (400)	912.1 (32)	940.5 (42)
753.9 (23)	774.0 (26)	756.2 (30)	779.5 (14)	743.4(27)	766.0 (23)	705.8 (57)	738.4 (75)
550.7 (1)	562.5 (2)	610.4 (9)	658.1 (11)	572.6 (20)	612.1 (26)	650.8 (52)	676.9 (41)
536.4 (0.7)	547.3 (1)	551.3 (1)	564.6 (1)	540.8 (1)	555.7 (0.8)	646.8 (1)	660.9 (2)
442.7 (26)	471.4 (41)	532.7 (0.8)	543.4 (1)	537.2 (1)	548.8 (2)	609.9 (1)	623.1 (2)
436.9 (18)	452.4 (4)	460.3 (8)	474.2 (9)	405.2 (12)	423.5 (14)	510.7 (49)	532.0 (43)
350.0 (4)	358.9 (4)	363.5 (0.8)	372.3 (0.8)	362.6 (2)	372.9 (2)	440.4 (0.9)	450.3 (0.9)
312.6 (3)	318.7 (2)	317.3 (0.4)	324.8 (0.4)	310.4 (0.2)	321.0 (0.2)	371.2 (42)	386.7 (30)
253.4 (0.9)	263.9 (0.6)	259.3 (0.3)	263.0 (0.2)	254.5 (2)	265.1 (2)	231.5 (4)	241.9 (3)
126.1 (0.6)	128.4 (0.6)	171.9 (2)	175.9 (2)	194.0 (3)	197.3 (3)	181.7 (1)	184.8 (1)
57.7 (2)	58.2 (2)	52.4 (< 0.1)	53.2 (< 0.1)	139.7 (0.2)	142.9 (0.2)	58.4 (< 0.1)	60.6 (< 0.1)
35.8 (0.7)	35.1 (0.7)	41.2 (< 0.1)	48.6 (< 0.1)	46.5 (0.3)	48.1 (0.3)	32.3 (0.1)	33.9 (0.1)

**Table S1.** Calculated IR frequencies (cm<sup>-1</sup>) and intensity (km mol<sup>-1</sup>, in parentheses) of CF<sub>3</sub>SSO• and its isomers at the MPW1PW91 and B3LYP methods using 6-311+G(3df) basis set.

CF₃S●			•CF <sub>2</sub> SF		
MPW1PW91	B3LYP	BP86	MPW1PW91	B3LYP	BP86
1181.2 (255)	1134.1 (253)	1071.9 (243)	1339.9 (300)	1304.4 (314)	1271.1 (326)
1172.0 (282)	1123.7 (284)	1055.9 (329)	1278.6 (246)	1232.9 (244)	1173.6 (232)
1136.4 (370)	1102.5 (359)	1040.4 (276)	734.9 (4)	721.3 (4)	714.9 (7)
778.5 (11)	758.2 (10)	727.9 (8)	592.8 (159)	522.3 (155)	478.9 (88)
545.3 (2)	535.0 (1)	512.4 (1)	500.0 (16)	489.8 (13)	466.8 (58)
543.8 (0.5)	532.6 (0.3)	509.2 (< 0.1)	392.2 (4)	391.7 (8)	413.1 (13)
459.1 (3)	445.8 (3)	431.8 (2)	373.9 (0.3)	367.1 (0.2)	353.4 (1)
293.3 (0.3)	288.8 (0.3)	270.4 (0.3)	183.1 (3)	177.6 (3)	157.7 (2)
207.9 (0.5)	201.7 (0.6)	198.4 (0.7)	105.0 (1)	115.8 (1)	131.8 (2)

**Table S2.** Calculated IR frequencies  $(cm^{-1})$  and intensity (km mol<sup>-1</sup>, in parentheses) of  $CF_3S$ • at the MPW1PW91, B3LYP and BP86 methods using 6-311+G(3df) basis set.

Table S3. Calculated vertical transitions (nm) for  $CF_3S\bullet$ .

EOM <sup>[a]</sup>	CASSCF <sup>[b]</sup>	MRCI+Q	TD-B3LYP <sup>[c]</sup>
19410 (0)	17854.0	22960	11092.1 (0)
322.4 (0.0029)	287.3	324.9	370.9 (0.0006)
211.3 (0)	164.7	178.3	236.8 (0.0006)
181.2 (0.0012)			225.5 (0)
			212.7 (0.0001)
			209.6 (0.0094)
			193.9 (0.0001)

[a] At the EOM-CCSD/aug-cc-pV(T+d)Z level of theory. The oscillator strengths are given in parentheses. [b] The CASSCF/aug-cc-pv(T+d)z active space is (21,15) and all CI configurations with weight greater than 0.01 were considered. Calculation were done in  $C_s$  symmetry at the optimized equilibrium geometry at CCSD(T)/aug-cc-pv(T+d)z. [c] At the 6-311+G(3df) basis set.

Table 4. Comput	ed and observed in data	IOF • $CF_2SF$ .	
$v_{cal}^{[a]}$	V <sub>obs</sub> <sup>[b]</sup>		Mode <sup>[c]</sup>
CCSD(T)	N <sub>2</sub> -matrix	Ar-matrix	•CF <sub>2</sub> SF
1315.3	1301.9	1299.1	v <sub>1</sub> , v <sub>s</sub> (CF <sub>2</sub> )
1265.5	1237.2	1232.6	$v_2$ , $v_{as}(CF_2)$
712.4	713.2	710.7	ν <sub>3</sub> , ν(CS)
623.3	578.1	583.4	v <sub>4</sub> , v(SF)
494.4	491.4	490.3	ν <sub>5</sub> , δ(CF <sub>2</sub> )

Table 4. Computed and observed IR data for •CF<sub>2</sub>SF.

[a] Harmonic IR frequencies calculated harmonic frequencies at the aug-cc-pV(T+d)Z basis set. [b] Observed band positions for the most intense matrix sites. [c] Tentative assignment of the vibration modes based on the computed vibrational displacement vectors for  $\bullet$ CF<sub>2</sub>SF.

$v_{cal}^{[a]}$	V <sub>obs</sub> <sup>[b]</sup>		$\Delta v (O/^{18}O)^{[c]}$		Mode <sup>[d]</sup>
CCSD(T)	N <sub>2</sub> -matrix	Ne-matrix	obs	cal	
1172.9	1185.1	1189.5	< 0.5	0.2	$v_1, v_{as}(CF_3)$
1169.2	1176.1	1183.8	< 0.5	-0.1	v <sub>2</sub> , v <sub>as</sub> (CF <sub>3</sub> )
1118.9	1124.1	1126.9	< 0.5	0.4	v <sub>3</sub> , v <sub>s</sub> (CF <sub>3</sub> )
1013.7	1017.6	1016.6	55.5	56.2	v <sub>4</sub> , v(OO)
741.0	764.4	765.1	0.5	-0.1	ν <sub>5</sub> , δ(CF <sub>3</sub> )
584.4	558.6	559.0	18.8	28.6	v <sub>6</sub> , v(SO)
539.6	n.o. <sup>[e]</sup>	n.o. <sup>[e]</sup>	n.o.	0.1	ν <sub>7</sub> , δ(CF <sub>3</sub> )
520.2	540.0	539.7	< 0.5	0.3	ν <sub>8</sub> , δ(CF <sub>3</sub> )
461.0	463.3	465.1	< 0.5	5.6	v <sub>9</sub> , v(CS)

Table S5. Computed and observed IR data for CF<sub>3</sub>SOO•.

[a] Harmonic IR frequencies (> 400 cm<sup>-1</sup>) calculated at the aug-cc-pV(D+d)Z basis set. Full list of the calculated IR frequencies is given in Table S7. [b] Observed band positions for the most intense matrix sites. [c] Observed and calculated <sup>18</sup>O-isotopic shifts. [d] Tentative assignment of the vibration modes based on the computed vibrational displacement vectors. [e] Not observed due to low intensity.

### **Table S6.** Calculated vertical transitions (nm) for CF<sub>3</sub>SOO•.

EOM <sup>[a]</sup>	CASSCF <sup>[b]</sup>	TD-B3LYP <sup>[c]</sup>
1211 (0)	1227	1045.2 (0)
354.4 (0)	398.6	437.3 (0.0005)
302.7 (0.0022)	386.2	392.1 (0)
295.8 (0.0003)		342.2 (0.0012)
		303.5 (0.0006)
		283.8 (0.0006)
		252.9 (0.0170)
		229.3 (0.1240)
		217.4 (0.0001)
		207.4 (0.0006)

[a] At the EOM-CCSD/aug-cc-pV(T+d)Z level of theory. The oscillator strengths are given in parentheses. [b] CASSCF/aug-cc-pv(D+d)Z with an active space (15,14). [c] At the 6-311+G(3df) basis set.

CF <sub>3</sub> SOO∙			CF <sub>3</sub> OSO●			$CF_3SO_2\bullet$		
MPW1PW91	B3LYP	BP86	MPW1PW91	B3LYP	BP86	MPW1PW91	B3LYP	BP86
1210.8 (217)	1164.6 (219)	1279.9 (226)	1281.7 (402)	1236.2 (408)	1172.3 (371)	1350.9 (221)	1301.3 (217)	1239.8 (208)
1207.0 (255)	1162.0 (256)	1093.6 (237)	1243.7 (226)	1206.5 (183)	1158.2 (121)	1267.7 (157)	1224.4 (263)	1168.9 (277)
1156.8 (58)	1116.0 (117)	1074.1 (118)	1217.5 (242)	1170.6 (264)	1109.7 (267)	1267.7 (283)	1223.4 (177)	1168.3 (149)
1129.9 (358)	1090.6 (307)	1028.5 (404)	1175.2 (526)	1136.9 (547)	1081.6 (587)	1144.3 (19)	1101.7 (12)	1046.6 (15)
780.3 (14)	760.3 (14)	730.3 (15)	948.7 (76)	919.7 (67)	872.1 (54)	1081.4 (352)	1043.8 (371)	989.6 (351)
623.0 (4)	579.0 (8)	563.5 (18)	761.1 (91)	729.1 (88)	685.4 (88)	758.3 (28)	734.7 (33)	701.6 (36)
565.1 (0.9)	552.8 (0.5)	512.7 (0.3)	659.9 (1)	646.2 (0.5)	617.4 (0.4)	564.4 (2)	551.1 (1)	524.9 (0.5)
544.6 (1)	534.1 (0.9)	511.5 (7)	626.5 (5)	613.4 (4)	584.1 (2)	551.7 (1)	539.5 (0.8)	515.3 (0.4)
469.0 (8)	454.6 (7)	403.3 (10)	544.8 (43)	527.3 (48)	503.6 (50)	499.2 (38)	487.8 (36)	459.3 (29)
421.0 (0.1)	390.3 (0.6)	335.8 (15)	473.3 (7)	462.0 (7)	437.1 (6)	450.2 (20)	431.9 (19)	402.7 (14)
325.1 (0.4)	317.0 (0.5)	300.5 (0.1)	406.4 (19)	397.6 (24)	378.5 (22)	334.9 (0.3)	322.7 (0.2)	300.6 (0.2)
297.3 (0.2)	284.7 (0.7)	202.4 (16)	315.1 (2)	304.0 (3)	286.6 (4)	276.9 (1)	256.5 (1)	232.8 (1)
172.8 (1)	166.2 (0.9)	115.2 (0.2)	178.4 (1)	175.9 (1)	165.0 (1)	203.7 (5)	198.1 (4)	181.4 (3)
69.4 (0.4)	60.3 (0.4)	66.2 (< 0.1)	73.3 (1)	<b>69.3 (1</b> )	60.9 (0.8)	171.9 (1)	168.8 (1)	154.8 (1)
52.2 (0.3)	50.8 (0.4)	30.6 (< 0.1)	37.7 (3)	36.1 (3)	32.1 (3)	50.2 (0.3)	47.4 (0.3)	42.9 (0.3)

**Table S7.** Calculated IR frequencies (cm<sup>-1</sup>) and intensity (km mol<sup>-1</sup>, in parentheses) of CF<sub>3</sub>SOO•, CF<sub>3</sub>OSO• and CF<sub>3</sub>SO<sub>2</sub> at the MPW1PW91, B3LYP and BP86 methods using 6-311+G(3df) basis set.

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EOM<sup>[a]</sup> CASSCF<sup>[b]</sup> TD-B3LYP<sup>[c]</sup> MRCI+Q 526.4 (0.0011) 612 641.0 592.8 (0.0015) 278.5 (0.0212) 264 281.7 316.3 (0.0219) 241.7 (0.0090) 271.4 (0.0018) 238.0 (0.0075) 267.6 (0.0036) 227.7 (0.0047) 210.3 (0.0337) 202.1 (0.0173) 198.3 (0.0101) 194.0 (0.0142) 190.5 (0.0302)

Table S8. Calculated vertical transitions (nm) for •CF<sub>2</sub>SF.

[a] At the EOM-CCSD/aug-cc-pV(T+d)Z level of theory. The oscillator strengths are given in parentheses. [b] The CASSCF/aug-cc-pv(T+d)z active space is (15,13) and all CI configurations with weight greater than 0.02 were considered. Calculation were done in  $C_1$  symmetry using at the optimized equilibrium geometry at CCSD(T)/aug-cc-pv(T+d)z. [c] At the 6-311+G(3df) basis set.

Calculated atomic coordinates (in Angstroms) and energies (in Hartrees) for all optimized structures.

CF₃S●			
B3LYP/6-31	.1+G(3df)		
С	-0.32581400	-0.02808700	0.0000000
F	-0.80668100	1.22351300	0.0000000
F	-0.80668100	-0.66249000	1.07580600
F	-0.80668100	-0.66249000	-1.07580600
S	1.48345400	0.06760700	0.0000000
Zero-point	correction=	0.	.013949
Thermal co	prrection to En	ergv=	0.018602
Thermal co	prrection to En	thalpv=	0.019546
Thermal co	prrection to Gil	bbs Free Energ	v= -0.015216
Sum of ele	ctronic and zer	ro-point Fnerg	ies= -735.921357
Sum of ele	ctronic and the	ermal Energies	= -735 916704
Sum of ele	ctronic and the	ermal Enthalni	es= -735 915760
Sum of ele	ctronic and the	ermal Eree Ene	$r_{3} = -735,9500$
Juin of ele			igies755.550522
	aug-cc-nV/(T+d	)7	
s			0 0000000
C 2	0.00000000	0.000000000	1 8152/773
с с	1 27100872	0.00000000	2 22185027
г с	0.60579519	1 07949777	2.23103027
r r	0.00370510	1.07040777	2.32241142
Г	-0.00778508	-1.00052598	2.51740908
	1.0(2.45)		
B3LYP/0-31	.1+G(30T)	0 77424000	0 47265200
	-1.03407600	-0.77431900	0.47265300
	-0.72133800	-0.02388600	-0.11150100
F C	-1.16084200	1.20618300	-0.24054800
5	0.82815300	-0.50378300	-0.41755100
F	1.80353800	0.4/96/400	0.58454100
Zero-point	correction=	0.	.012127
Thermal co	prrection to En	ergy=	0.017491
Thermal co	prrection to En	thalpy=	0.018436
Thermal co	prrection to Gil	bbs Free Energ	y= -0.018007
Sum of ele	ctronic and zei	ro-point Energi	ies= -735.879753
Sum of ele	ctronic and the	ermal Energies	-735.874389
Sum of ele	ctronic and the	ermal Enthalpi	es= -735.873445
Sum of ele	ctronic and the	ermal Free Ene	rgies= -735.909888
UCCSD(T)/	aug-cc-pV(T+d	)Z ENERGY=-7	34.91431399
C -0.04	429281150	-0.156196533	7 -0.7198102422
S -0.44	185182969	-0.475654127	5 0.8669300206
F 0.42	208327208	0.6392234865	5 1.7537904493
F 1.18	88871911	-0.2068719214	4 -1.1822474243
F -0.82	257010557	0.4690688276	5 -1.5794243528
cis-CF₃SOO	)•		
B3LYP/6-31	.1+G(3df)		
С	0.91428100	0.12648600	-0.00471000

С	0.91428100	0.12648600	-0.00471000
S	-0.46963000	-1.06330800	-0.10939700

S21

F	1.99452400	-0.53012600	-0.44624	1400	
F	0.72465800	1.20473600	-0.76204	100	
F	1.14214900	0.54210300	1.24027	200	
0	-1.69922100	0.01534100	0.5418	5300	
0	-2.39122500	0.64760900	-0.3555	1000	
Zero-point	correction=	C	0.019784		
Thermal co	prrection to En	ergy=	0.027	034	
Thermal co	prrection to En	ithalpy=	0.027	7978	
Thermal co	prrection to Gi	bbs Free Ener	gy= -	0.013981	
Sum of ele	ctronic and ze	ro-point Energ	gies=	-886.301457	
Sum of ele	ctronic and th	ermal Energie	s=	-886.294206	
Sum of electronic and thermal Enthalpies= -886.293262					
Sum of ele	ctronic and th	ermal Free En	ergies=	-886.335222	)

UCCSD(T)/aug-cc-pV(D+d)Z ENERGY=-884.66375315

0.1328123766	-1.1154751219	-0.4765464492
0.0023292982	0.1154543298	0.8569533791
-0.5549494095	-0.0311232565	-1.7183814540
0.4547185389	-0.4861732350	1.9847971132
-1.2669867673	0.5239284347	1.0645022702
0.7463763539	1.2160626207	0.6247773523
0.3653109474	0.6908276336	-2.3327941121
	0.1328123766 0.0023292982 -0.5549494095 0.4547185389 -1.2669867673 0.7463763539 0.3653109474	0.1328123766-1.11547512190.00232929820.1154543298-0.5549494095-0.03112325650.4547185389-0.4861732350-1.26698676730.52392843470.74637635391.21606262070.36531094740.6908276336

# trans-CF<sub>3</sub>SOO•

B3LYP/6-311+G(30f)					
С	1.00054400	-0.08531200	0.000074	400	
S	-0.52902100	0.91122900	-0.00018	800	
F	2.00965800	0.79413800	0.000375	500	
F	1.10649500	-0.86339700	1.075424	400	
F	1.10694400	-0.86320100	-1.07537	500	
0	-1.59797500	-0.51006100	-0.00085	5100	
0	-2.84537500	-0.19939400	0.00069	500	
Zero-poin	t correction=	C	0.019656		
Thermal c	Thermal correction to Energy= 0.027127				
Thermal correction to Enthalpy= 0.028071					
Thermal correction to Gibbs Free Energy= -0.015684					
Sum of electronic and zero-point Energies= -886.300701					
Sum of electronic and thermal Energies= -886.293230					
Sum of electronic and thermal Enthalpies= -886.292286					
Sum of ele	ectronic and th	ermal Free En	ergies=	-886.336041	

### CF₃OSO•

B3LYP/6-311+G(3df)					
С	-1.02415300	-0.03570100	-0.01897700		
F	-2.04660700	-0.15836100	-0.85368500		
F	-0.86119300	-1.18516300	0.64055500		
F	-1.31903200	0.90984500	0.88467600		
0	2.29078400	-0.77842800	-0.01087000		
0	0.07941800	0.29760600	-0.75453600		
S	1.57654900	0.49774300	0.01207500		
Zero-point correction= 0.021942					
Thermal correction to Energy= 0.028730					

Thermal correction to Enthalpy=0.029674Thermal correction to Gibbs Free Energy=-0.011648Sum of electronic and zero-point Energies=-886.436063Sum of electronic and thermal Energies=-886.429275Sum of electronic and thermal Enthalpies=-886.428331Sum of electronic and thermal Free Energies=-886.469653

### CF<sub>3</sub>SO<sub>2</sub>●

B3LYP/6-311+G(3df)

С	0.88755500	-0.00004200	-0.007467	700
0	-1.50034900	-1.27138000	-0.19502	400
F	1.40285000	1.08456800	0.542965	00
F	1.40338700	-1.08278500	0.545364	00
F	1.10767700	-0.00142200	-1.309687	'00
S	-1.03369400	0.00001100	0.322475	00
0	-1.50108200	1.27098400	-0.195298	800
Zero-point	correction=	C	0.021947	
Thermal c	orrection to Er	nergy=	0.0287	59
Thermal c	orrection to Er	nthalpy=	0.0297	704
Thermal c	orrection to Gi	ibbs Free Ener	gy= -0.	010863
Sum of ele	ectronic and ze	ro-point Energ	gies=	-886.397604
Sum of electronic and thermal Energies= -886.390791				
Sum of ele	ectronic and th	ermal Enthalp	ies=	-886.389847
Sum of ele	ectronic and th	ermal Free En	ergies=	-886.430413

### CF<sub>3</sub>SSO•

B3LYP/6-311+G(3df)				
С	1.21024900	0.15000600	0.00657	600
F	0.99818100	1.27294400	-0.68026	200
F	1.32557400	0.48219200	1.29644	800
F	2.36906200	-0.38124000	-0.39569	000
S	-0.09279900	-1.11381900	-0.28042	2700
S	-1.79414900	-0.08158300	0.46042	400
0	-2.41320800	0.73266900	-0.6129	8500
Zero-point correction= 0.019014				
Thermal correction to Energy= 0.026581				
Thermal correction to Enthalpy= 0.027525				
Thermal correction to Gibbs Free Energy= -0.015918				
Sum of electronic and zero-point Energies= -1209.406697				
Sum of electronic and thermal Energies= -1209.399129				
Sum of electronic and thermal Enthalpies= -1209.398185				
Sum of electronic and thermal Free Energies= -1209.441628				

### **CF**<sub>3</sub>SOS●

B3LYP/6	5-311+G(3df)		
С	1.23770100	-0.17858100	-0.00905800
F	2.33809100	0.28677600	-0.61486600
F	0.87366200	-1.32251000	-0.59374200
F	1.53135500	-0.45775700	1.26075500
S	-0.01743300	1.13336900	-0.17963500
0	-1.27508600	0.34790800	0.65928500

S-2.47716000-0.40026600-0.17594300Zero-point correction=0.018891Thermal correction to Energy=0.026278Thermal correction to Enthalpy=0.027222Thermal correction to Gibbs Free Energy=-0.015747Sum of electronic and zero-point Energies=-1209.352900Sum of electronic and thermal Energies=-1209.345512Sum of electronic and thermal Enthalpies=-1209.344568Sum of electronic and thermal Free Energies=-1209.387537

### CF₃S(O)S●

- 3-(-/-					
B3LYP/6-311+G(3df)					
С	-1.07648000	-0.22174400	0.01210	0080	
F	-1.21913200	-0.41574700	1.31307	7800	
F	-1.18167600	-1.37282900	-0.63216	5800	
S	0.63268400	0.56802300	-0.37388	3100	
0	0.59151200	1.88882500	0.26056	5900	
S	1.95452800	-0.77106100	0.08980	0300	
F	-2.00681600	0.61840600	-0.41557	7000	
Zero-point correction= 0.019947					
Thermal correction to Energy= 0.027139					
Thermal correction to Enthalpy= 0.028083					
Thermal correction to Gibbs Free Energy= -0.013724					
Sum of electronic and zero-point Energies= -1209.373889					
Sum of electronic and thermal Energies= -1209.366698					
Sum of electronic and thermal Enthalpies= -1209.365753					
Sum of ele	Sum of electronic and thermal Free Energies= -1209.407560				

### CF<sub>3</sub>OSS●

B3LYP/6-311+G(3df)					
С	1.34597000	-0.10034300	-0.02158	300	
F	2.33693500	-0.45234200	-0.83390	600	
F	1.05227900	-1.14147800	0.76915	200	
F	1.77956500	0.89093000	0.77389	700	
S	-2.42714200	-0.55504900	0.00008	000	
0	0.29442400	0.28124700	-0.79238	200	
S	-1.13224700	0.84742900	0.00531	200	
Zero-point correction= 0.020284					
Thermal correction to Energy= 0.027377					
Thermal correction to Enthalpy= 0.028321					
Thermal correction to Gibbs Free Energy= -0.014279					
Sum of electronic and zero-point Energies= -1209.424484					
Sum of electronic and thermal Energies= -1209.417392					
Sum of electronic and thermal Enthalpies= -1209.416448					
Sum of electronic and thermal Free Energies= -1209.459047					

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